The Crystal Structure of a New MnP₄ Modification Determined by Direct Methods Applied to Powder Data

BENGT I. NOLÄNG and LARS-ERIK TERGENIUS

Institute of Chemistry, University of Uppsala, Box 531, S-751 21 Uppsala, Sweden

In the phosphorus-rich part of the Mn-P system the occurrence of the phases MnP₃ and MnP₄ has been reported. The structure of MnP₃ is not known. In attempts to grow crystals of this compound, a new triclinic modification of MnP₄ was obtained. The present paper reports the determination of the crystal structure of this phase using direct methods applied to X-ray powder diffraction data. A complete single-crystal structure refinement based on X-ray diffractometer intensity data is in progress and a more detailed discussion of the triclinic MnP₄ structure is deferred to a forthcoming paper.

Experimental. The MnP₄ sample was prepared from red phosphorus (Koch-Light, claimed purity 99.999 % and electrolytic manganese (99.9 % further purified by a sublimation process) by heating the powdered elements (molar ratio 1:4) in an evacuated and sealed silica tube at 730 °C for 320 h. The powder was then used as feedstock in chemical vapour transport experiments. Silica tubes with a length of 13 cm and an internal diameter of 6 mm were used. The transporting component used was iodine with a filling concentration of 3.9 mol m⁻³ (I_2) . The source temperature was 735 °C and crystals of MnP₄ were formed in the coldest part of the tube at temperatures of 620-585 °C. The crystals were in the shape of long thin plates and were heavily twinned. No traces of the monoclinic form² were found. The powder pattern was indexed from preliminary single-crystal parameters. Refined lattice parameters were determined from a leastsquares refinement of Q-values $(=1/d^2)$ obtained from a Guinier-Hägg powder film. The exposure was performed at 25 °C using monochromatized $CrK\alpha_1$ radiation (λ =2.289753 Å) and with silicon (a = 5.431065 Å) as the internal calibration standard. The cell dimensions are: a = 5.8622(3) Å, b = 5.1059(3)Å, c = 5.8360(4) Å, $\alpha = 93.803(4)^{\circ}$, $\beta = 107.338(4)^{\circ}$, $\gamma = 115.830(5)^{\circ}$

Because of the similarity between this new triclinic modification of MnP₄ and the monoclinic form, ² the cell was chosen such that the triclinic ab plane corresponds to the ab plane in the monoclinic MnP₄, where $a(\text{monocl.}) \approx 2a(\text{tricl.}) + b(\text{tricl.})$ and $b(\text{monocl.}) \approx b(\text{tricl.})$. The numbers of formula

units in the monoclinic and the triclinic cell are 16 and 2, respectively. The corresponding cell volumes are 1163.8(1) Å³ and 146.08(2) Å³.

The intensity profile was measured on a SAAB Mk II Model 2 automatic film scanner ³ coupled on-line to an IBM 1800 computer. In all 70 reflections with sin $\theta/\lambda < 0.306$ were covered by the profile.

Structure determination and refinement. The integrated intensities for the 35 strongest reflections were evaluated using the computer program LINNE.⁴ For a few overlapping reflections the intensities were attributed to the appropriate reflections according to intensity ratios estimated from Weissenberg photographs. The structure was (provisionally)

Table 1. Evaluation of a Guinier-Hägg powder pattern of MnP_4 (triclinic). The Q-values have been multiplied by 10^6 .

H K L	D (O BS)	9(085)	Q(CALC)	I (OBS)	I (CALC)
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2 -1 -6	2.7893	128529	128576	92	℃0.3
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1 2 -5	1.7294	334364	334283	ĕ	ŧ
3 -1 -2	1.7294 1.7249 1.7031 1.6804	334364 336104 344743 354158	336165 344741 354198	2 0.1	2 6
2 -3 0	1.6804	354 <u>1</u> 58	354198 358837	0.1	0.1 0.2
į - į į	1.6656	360469	360473	33	3 9°
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1 -3 1	1.6541	365490	365328 372634	11	11

Table 2. Atomic parameters of MnP₄ (PI). All atoms are on position 2(i). The fractional coordinates are multiplied by 10³. The standard deviations are 2 units for all the positional parameters.

Atom	x	y	z	$B(Å^2)$
Mn	228	224	756	3.0(2)
P(1)	485	922	306	2.7(3)
P(2)	132	257	359	0.5(3)
P(3)	433	324	191	2.0(4)
P(4)	45	592	201	2.3(3)

assumed to be centrosymmetric and reflections with normalized structure factors greater than 0.9 (25 refl.) were included in the sign determination using the program MULTAN 71.⁵ Of the four solutions obtained, the one with the highest absolute figure of merit (1.46) was used in Fourier calculations, from which approximate coordinates for all atoms were obtained. It was later found that only two of the 25 signs were incorrectly determined. This is, to our knowledge, the first time that X-ray powder data have been used for a structure determination by means of direct methods.

For the final refinement the complete intensity profile was used (including the standard substance silicon) in a full profile refinement program.⁶ The function minimized is

$$\sum_{i} w_{i} [y_{i}(obs) - K^{-1}y_{i}(calc)]^{2}$$

where w_i is the weight assigned to an individual observed net intensity $y_i(obs)$, $y_i(calc)$ the calculated intensity and K is a scale factor. Scattering corrected for anomalous sion, were taken from the International Tables.7 A total of 37 parameters for the two phases were refined. These were: profile parameters: halfwidth (3+3), asymmetry (1+1), structure parameters: overall scale factor (1), lattice parameters (6+0), positional parameters (15+0), temperature factors (5+1), and "occupancy factor" for Si (1). The final agreement factors obtained (for definitions see Ref. 6) were: R(I) = 0.090, R(F) = 0.097, R(P) = 0.137, and R(WP) = 0.185. The largest deviation from zero in a final difference Fourier synthesis was equivalent to 5 % of a phosphorus peak in the F(obs) Fourier maps. A list of observed and calculated structure factors can be obtained on request from the authors.

The structure shows great similarities with the monoclinic MnP₄, which can be described as a stacking of eight MnP₄ layers parallel to the *ab* plane. The stacking sequence consists of four layers of almost the same kind followed by the same four layers rotated 180°. In the triclinic MnP₄ there are

only two layers, both of them of the same type. Twolayer structures are also found in CrP₄ and MoP₄, but in these compounds there are only two phosphorus sites in special positions. In the triclinic MnP₄ all four phosphorus atoms are in general positions. The manganese atoms are surrounded by six phosphorus atoms at distances ranging from 2.22 Å to 2.37 Å at the corners of a slightly distorted octahedron. Two of the phosphorus atoms are surrounded by two manganese atoms and two phosphorus atoms, while the other two phosphorus atoms are surrounded by one manganese and three phosphorus atoms in a distorted tetrahedral arrangement. The average P-P distance is 2.25 Å. The monoclinic form contains manganese pairs with an Mn – Mn distance of 2.94 Å.² Due to small differences between the layers in the two forms and the different stacking, the shortest Mn-Mn distance in the triclinic form is 3.21 Å.

Acknowledgements. The authors thank Prof. S. Rundqvist for his valuable criticism of the manuscript. Financial support from the Swedish Natural Science Research Council is gratefully acknowledged.

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Received February 19, 1980.